

DART  
WARS



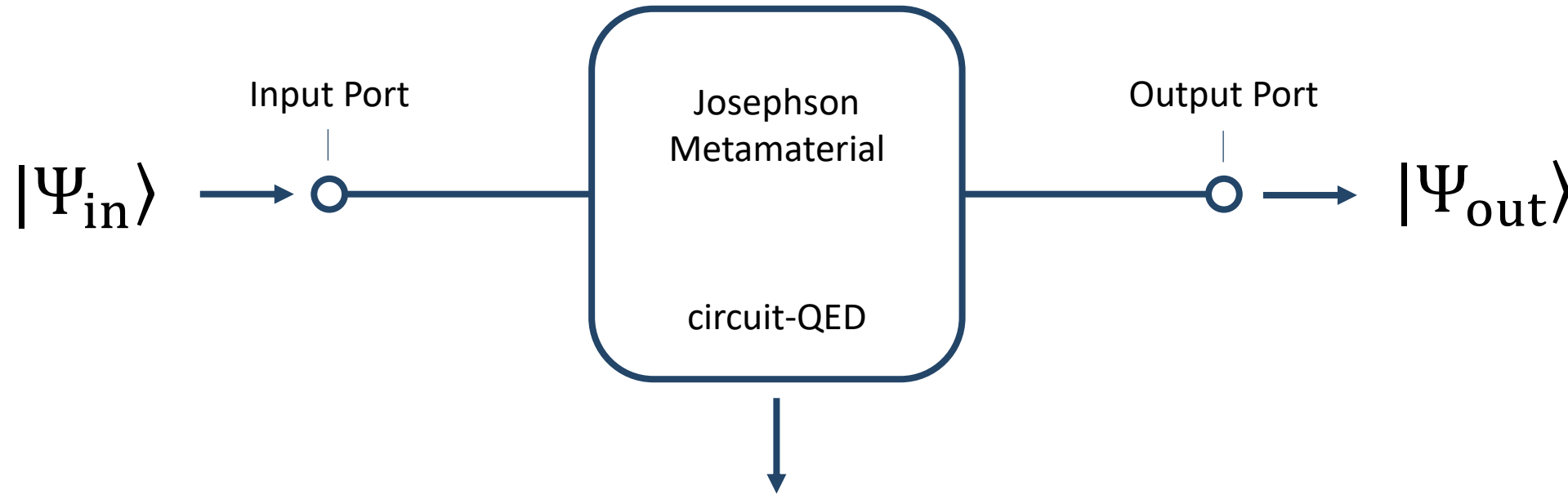
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# DART WARS Annual Meeting

## WP1: Design and Simulation

*Emanuele ENRICO*

# Outline



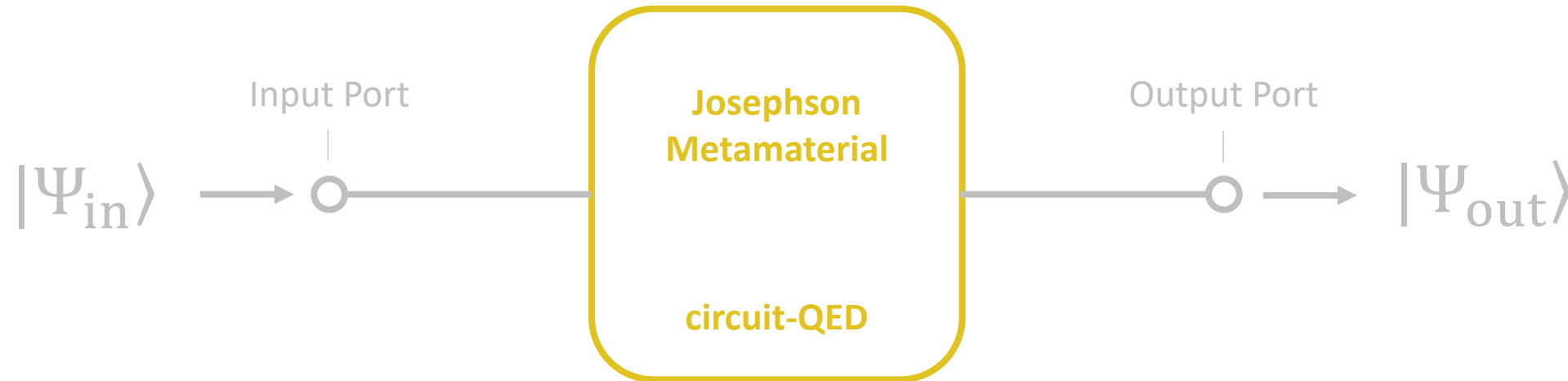
### Classic observables:

- Gain
- Noise Figure
- Noise Temperature

### Quantum behavior:

- Occupancy probability distribution

# Outline



Classic observables:

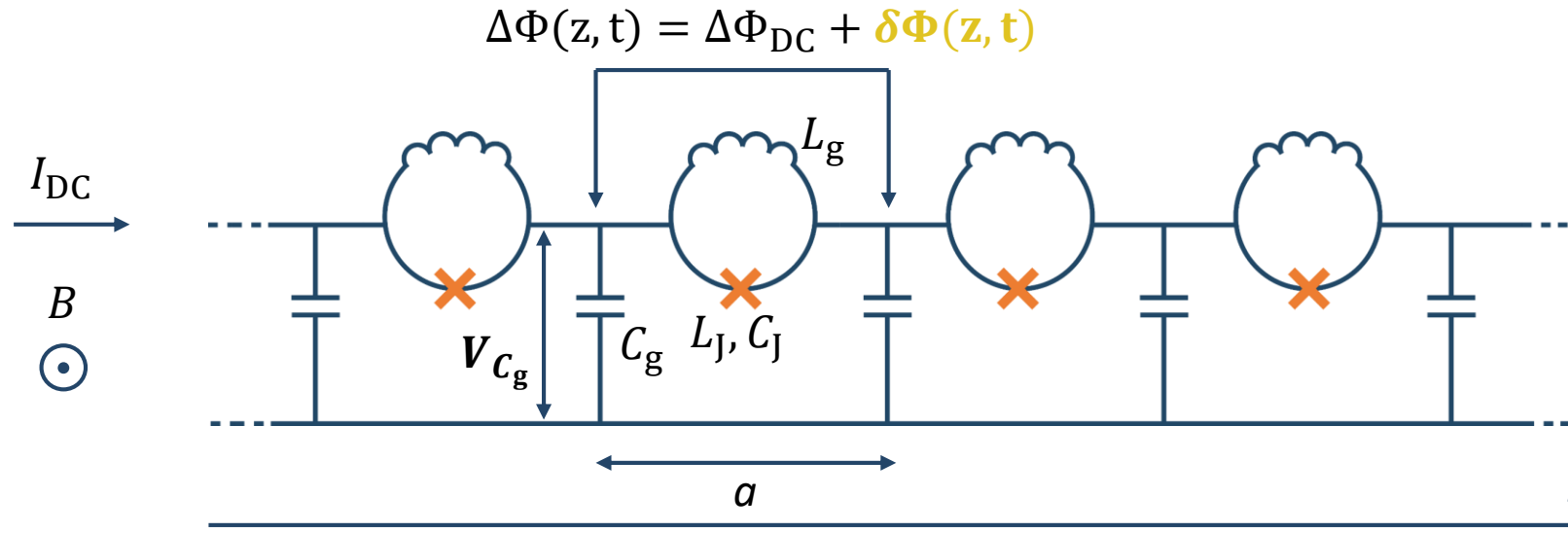
- Gain
- Noise Figure
- Noise Temperature

Quantum behavior:

- Occupancy probability distribution

# First Quantization Hamiltonian

We adapt and further extend the work presented in [1] to an **rf-SQUID based Josephson Traveling Wave Parametric Amplifier** [2]



$\Delta\Phi_{DC}$  is the **constant** flux difference due to external bias

$\delta\Phi(z, t)$  is the **time-dependent** flux difference induced by the travelling waves

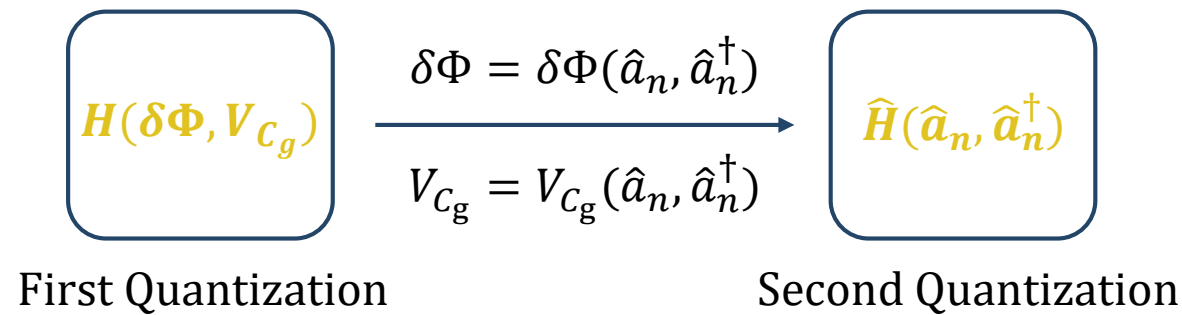
The **first quantization Hamiltonian** can be written as the sum of the electromagnetic energy stored in each component of the transmission line

$$H = \frac{1}{a} \int_0^{aN} \left[ \frac{1}{2L_g} \Delta\Phi(z, t)^2 + \varphi_0 I_c \left( 1 - \cos\left(\frac{\Delta\Phi(z, t)}{\varphi_0}\right) \right) + \frac{C_J}{2} \left( \frac{\partial \Delta\Phi(z, t)}{\partial t} \right)^2 + \frac{C_g}{2} V_{C_g}^2(z, t) \right] dz$$

[1] T. H. A. van der Reep, "Mesoscopic Hamiltonian for Josephson traveling-wave parametric amplifier", Phys. Rev. A **99**, 063838 (2019)

[2] A. B. Zorin, "Josephson Traveling-Wave Parametric Amplifier with Three-Wave Mixing", Phys. Rev. App. **6**, 034006 (2016)

# Second Quantization Hamiltonian



# Second Quantization Hamiltonian

The Hamiltonian describes all the **energy preserving interactions** between 3 or 4 traveling waves (i.e., the **parametric down conversion**, the **sum frequency generation**, the **high order harmonics generation**, etc..)

$$H = \hbar\chi_0 + \sum_n \hbar\chi_1^{(n)} \left( \hat{a}_n^\dagger \hat{a}_n + \frac{1}{2} \right) + \sum_{n,l,m} \hbar\chi_3^{(n,l,m)} \{ \hat{a} + \hat{a}^\dagger \}_{n,l,m} \cdot \delta_{\Delta_{n,l,m},0} + \sum_{n,l,m,s} \hbar\chi_4^{(n,l,m,s)} \{ \hat{a} + \hat{a}^\dagger \}_{n,l,m,s} \cdot \delta_{\Delta_{n,l,m,s},0}$$

Energy from  
**external bias**

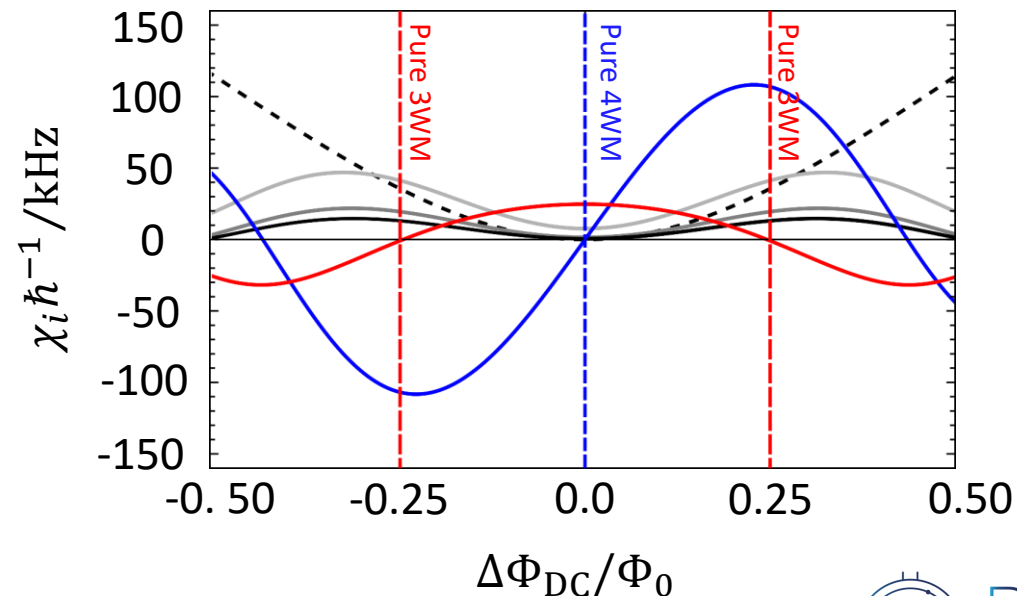
Energy of the  
**propagating waves**

All 3-wave mixing  
energy-preserving processes

All 4-wave mixing  
energy-preserving processes

For **parametric down-conversion**

- **3WM**  $n, l, m = \{p, s, i\}$   
with  $\omega_p = \omega_s + \omega_i$
- **4WM**  $n, l, m, s = \{p, s, j\}$   
with  $2\omega_p = \omega_s + \omega_j$



---  $\chi_0 \cdot 10^{-12}$

—  $(\chi_1^{(p)} - \omega_p) \cdot 10^{-5}$

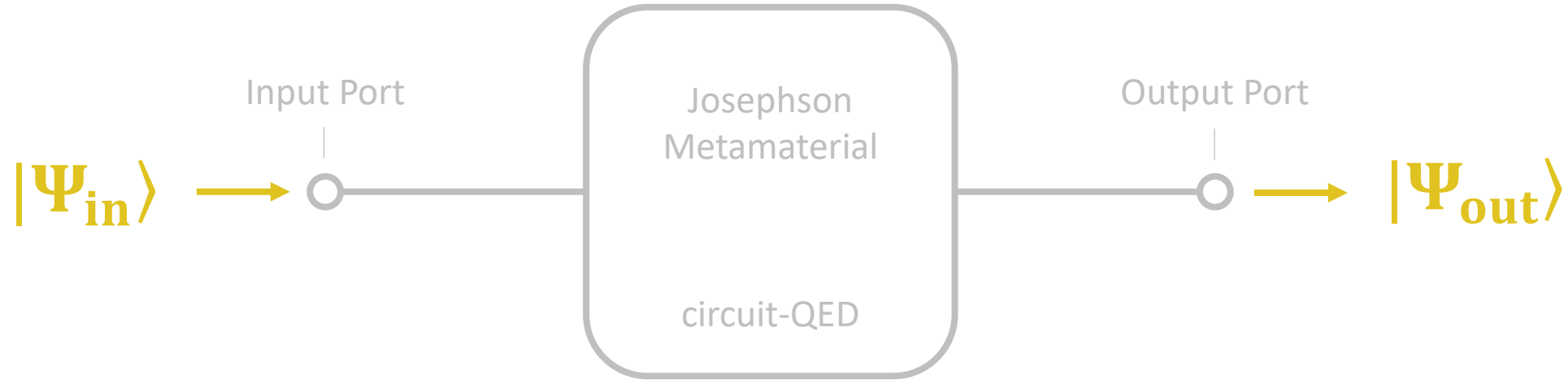
—  $(\chi_1^{(i)} - \omega_i) \cdot 10^{-5}$

—  $(\chi_1^{(s)} - \omega_s) \cdot 10^{-5}$

—  $\chi_3^{\{p,s,i\}} \cdot 10^{-2}$

—  $\chi_4^{\{p,p,s,j\}}$

# Outline



Classic observables:

- Gain
- Noise Figure
- Noise Temperature

Quantum behavior:

- Occupancy probability distribution

# CMEs from Heisenberg Equation

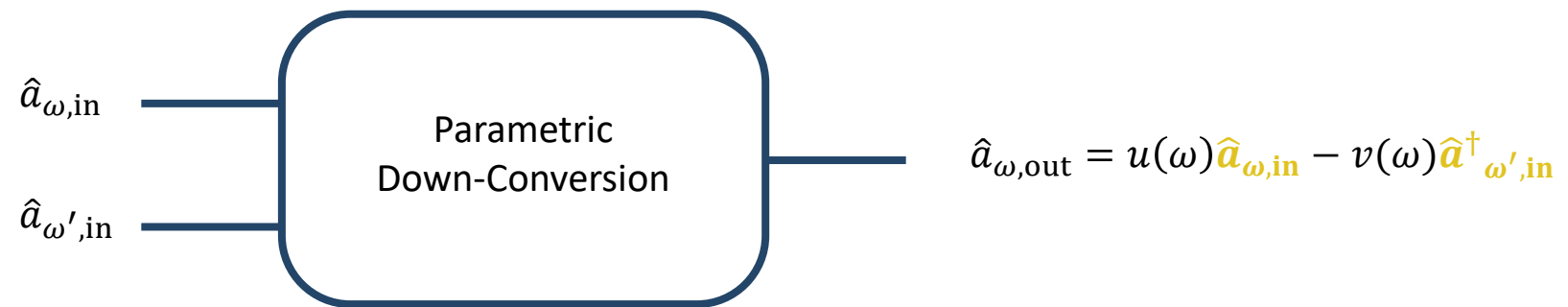
Selecting a proper bias condition, the amplifier can work as a pure 3-Wave Mixer or 4-Wave Mixer ( $H_{3WM}, H_{4WM}$ ). In this condition the **evolution of propagating modes** can be derived solving the **Heisenberg equation**:

$$\frac{d\hat{a}_n}{dt} = \frac{i}{\hbar} [H_{3WM(4WM)}, \hat{a}_n] + \frac{\partial \hat{a}_n}{\partial t} \quad \text{where } n = \{p, s, i, j\}$$

Under the **undepleted and classical pump** approximation, the output field at the **signal frequency  $\omega$**  is:

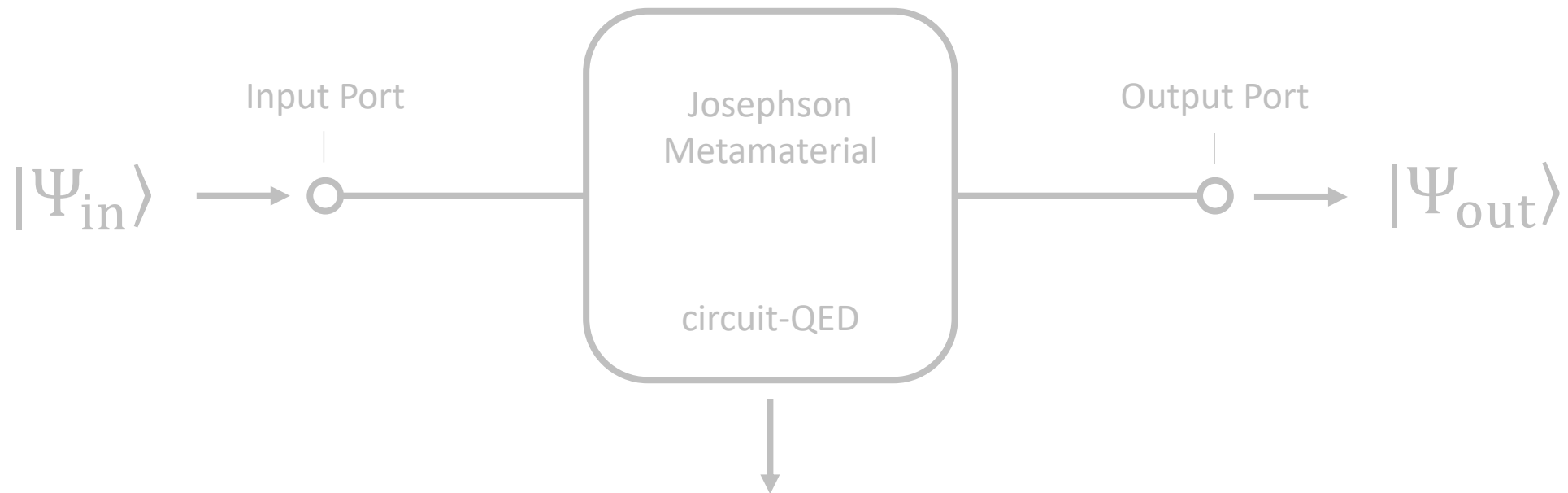
$$\hat{a}_\omega(t) = \left[ \left( \cosh(gt) + \frac{i\Psi}{2g} \sinh(gt) \right) \hat{a}_{\omega, \text{in}} - \left( \frac{iY}{g} \sinh(gt) \right) \hat{a}_{\omega', \text{in}}^\dagger \right] e^{-i\left(\frac{\Psi}{2}\right)t}$$

where  $g$  is the **complex gain factor**,  $\Psi$  is the **density phase mismatch** and  $Y$  is the **interaction parameter**.





# Outline



**Classic observables:**

- **Gain**
- **Noise Figure**
- **Noise Temperature**

Quantum behavior:

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# Signal photons at the output port

$$\langle \hat{n}_{\omega, \text{out}} \rangle = \langle \hat{a}_{\omega, \text{out}}^\dagger \hat{a}_{\omega, \text{out}} \rangle =$$

$$= |u(\omega)|^2 \langle \hat{n}_{\omega, \text{in}} \rangle + |v(\omega)|^2 \langle \hat{n}_{\omega', \text{in}} \rangle + i \left( u^*(\omega) v(\omega) \langle \hat{a}_{\omega, \text{in}}^\dagger \hat{a}_{\omega', \text{in}}^\dagger \rangle - u(\omega) v^*(\omega) \langle \hat{a}_{\omega', \text{in}} \hat{a}_{\omega, \text{in}} \rangle \right) + |v(\omega)|^2$$

**Amplification** of the input field at  $\omega$  frequency

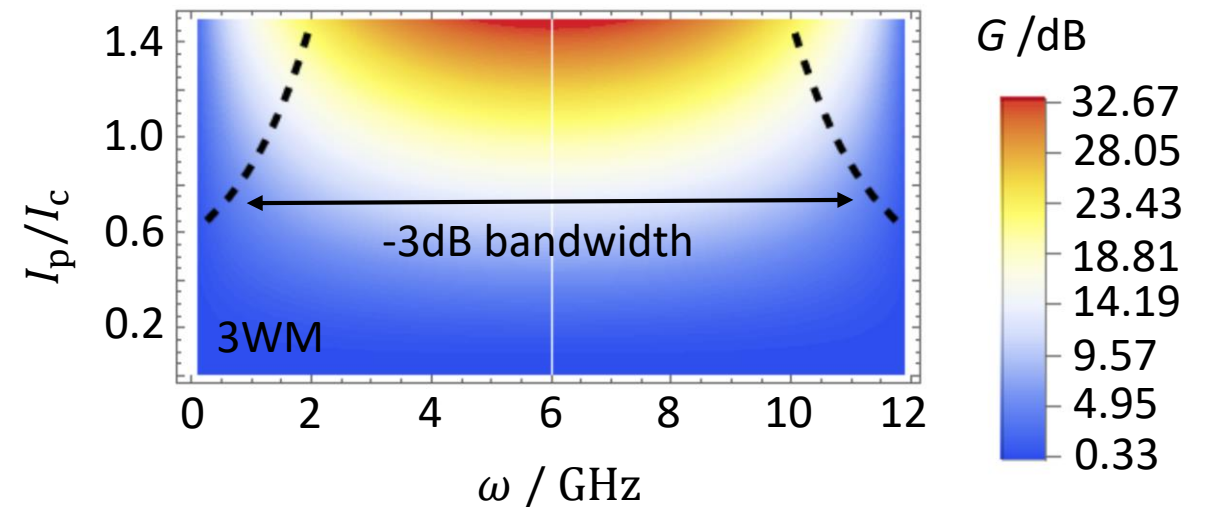
**Contribution** to the amplification of the **input field at  $\omega$**  frequency due to the presence of an input signal at  **$\omega'$  frequency**

$$G(\omega) \equiv \frac{\langle \hat{n}_{\omega, \text{out}} \rangle}{\langle \hat{n}_{\omega, \text{in}} \rangle} = |u(\omega)|^2$$

Contribution from the **spontaneous annihilation** of a pump photon

Contribution from the **spontaneous creation** of a pump photon

**Added noise photons** ( $\langle \text{vac} | \hat{n}_{\omega, \text{out}} | \text{vac} \rangle$ )



# Noise Figure

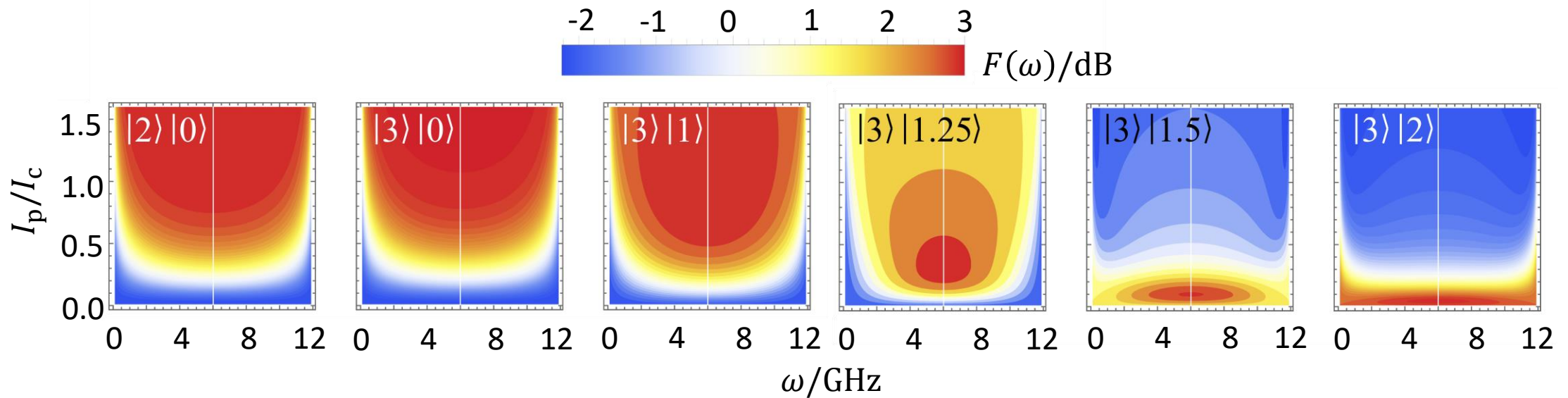
$$F(\omega) \equiv \frac{\text{SNR}_{\text{in}}(\omega)}{\text{SNR}_{\text{out}}(\omega)}$$

$$\text{SNR}_{\text{in}}(\omega) \equiv \frac{\langle \hat{n}_{\omega,\text{in}} \rangle^2}{\langle (\Delta \hat{n}_{\omega,\text{in}})^2 \rangle}$$

$$\text{SNR}_{\text{out}}(\omega) \equiv \frac{\langle \hat{n}_{\omega,\text{out}} \rangle^2 - \langle \hat{n}_{\omega,\text{out}}^{\text{vac}} \rangle^2}{\langle (\Delta \hat{n}_{\omega,\text{out}})^2 \rangle} \quad [4]$$

└ Variance of the input/output photon number ─

Supposing at the input a **Bimodal Coherent state**:  $|\Psi_C\rangle = D(\alpha_\omega)|0_\omega\rangle D(\alpha_{\omega'})|0_{\omega'}\rangle = |\alpha_\omega\rangle|\alpha_{\omega'}\rangle$



An **idler** tone at the input port **changes the Noise figure**  $F(\omega)$  of the amplifier

[4] Z. Shi *et al.*, "Quantum noise properties of non-ideal optical amplifiers and attenuators", *J. Opt.* **13** (2011)

# Noise Temperature

The **effective temperature**  $T_{\text{eff}}(\omega)$  of the amplifier is the temperature that a **Bose-Einstein distribution** should have to equal the output  $\omega$  mode occupancy generated by a vacuum input state [5]:

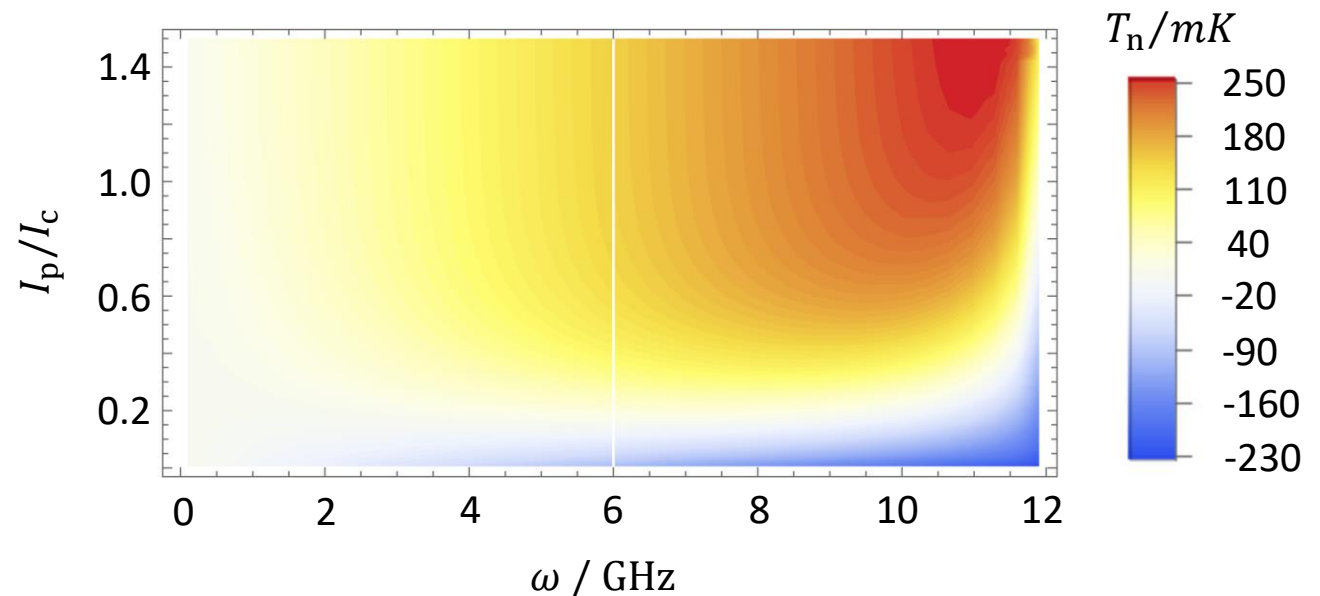
$$\frac{1}{e^{\hbar\omega/k_B T_{\text{eff}}(\omega)} - 1} = |v(\omega)|^2$$

The **noise temperature**  $T_n(\omega)$  is the effective temperature normalized on the gain minus the contribution given by the fluctuation of the input vacuum state:

$$T_n(\omega) = \frac{T_{\text{eff}}(\omega)}{G(\omega)} - \frac{1}{2} \frac{\hbar\omega}{k_B}$$

For high gain  $T_n(\omega)$  approaches the **Standard Quantum Limit**:

$$T_{n,\text{SQL}} = \frac{1}{2} \frac{\hbar\omega}{k_B}$$

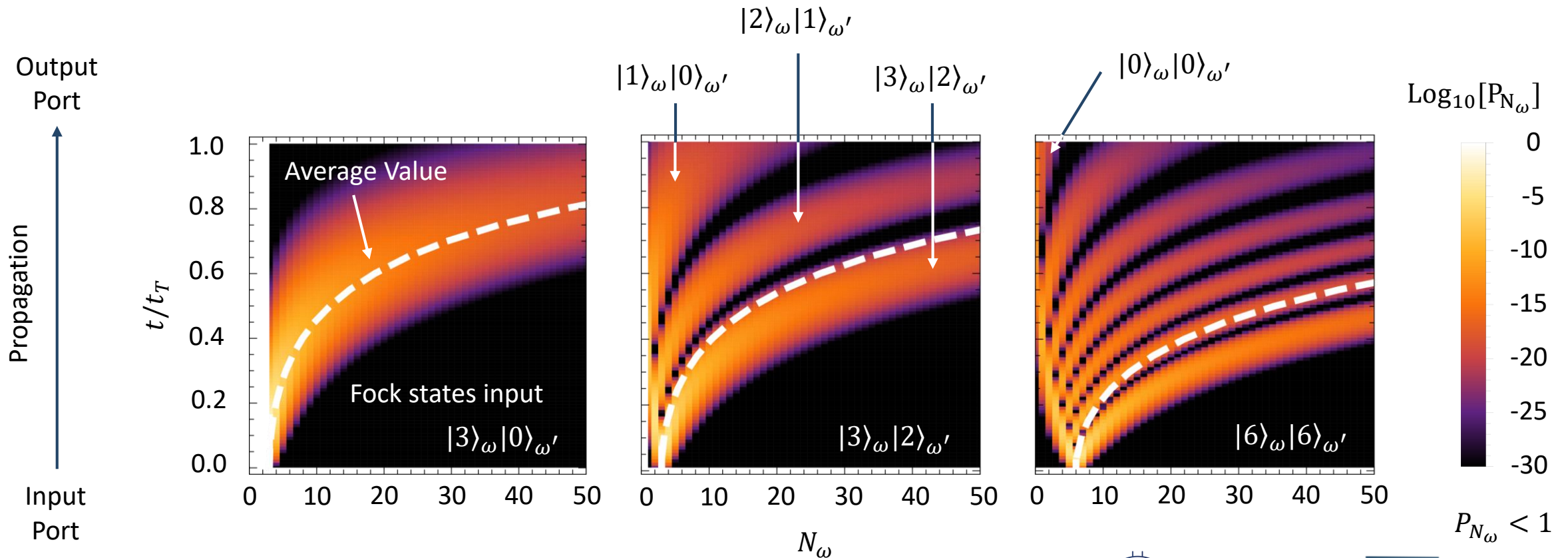


[5] A. A. Clerk *et al.*, “Introduction to quantum noise, measurement, and amplification”, *Rev. Mod. Phys.* **82**, 1155 (2010)

# Time-evolution of bimodal Fock states

The average photon number at frequency  $\omega$  at a certain time  $t$  can be written in terms of the **probability**  $P_{N_\omega}$  to find  $N_\omega$  photons at a given time

$$\langle n_\omega(t) \rangle = \sum_{N_\omega} P_{N_\omega}(t) \cdot N_\omega$$




# For more details...

## A quantum model for rf-SQUIDs based metamaterials enabling 3WM and 4WM Traveling Wave Parametric Amplification

Angelo Greco and Luca Fasolo  
 INRiM, Istituto Nazionale di Ricerca Metrologica, Strada delle Cacce 91, 10135 Torino, Italy and  
 Department of Electronics and Telecommunications,  
 PoliTb, Corso Castellfardo 39, 10129 Torino, Italy

Alice Meda, Luca Callegaro  
 INRiM, Istituto Nazionale di Ricerca Metrologica, Strada delle Cacce 91, 10135 Torino, Italy

Emanuele Enrico   
 INRiM, Istituto Nazionale di Ricerca Metrologica, Strada delle Cacce 91, 10135 Torino, Italy and  
 INFN, Trento Institute for Fundamental Physics and Applications, I-38123, Povo, Trento, Italy  
 (Dated: September 29, 2021)

A quantum model for Josephson-based metamaterials working in the Three-Wave Mixing (3WM) and Four-Wave Mixing (4WM) regimes at the single-photon level is presented. The transmission line taken into account, namely Josephson Traveling Wave Parametric Amplifier (JTWPA), is a bipole composed of a chain of rf-SQUIDs which can be biased by a DC current or a magnetic field to activate the 3WM or 4WM nonlinearities. The model exploits a Hamiltonian approach to analytically determine the time evolution of the system both in the Heisenberg and interaction pictures. The former returns the analytic form of the gain of the amplifier, while the latter allows recovering the probability distributions vs. time of the photonic populations, for multimodal Fock and coherent input states. The dependence of the metamaterial's nonlinearities is presented in terms of circuit parameters in a lumped model framework while evaluating the effects of the experimental conditions on the model validity.

arXiv:2009.01002v5

A. Greco *et al.*, “Quantum model for rf-SQUID based metamaterials enabling 3WM and 4WM Traveling Wave Parametric Amplification”. *Phys. Rev. B* 104, 184517 (2021).

## Bimodal Approach for Noise Figures of Merit Evaluation in Quantum-Limited Josephson Traveling Wave Parametric Amplifiers

L. Fasolo, C. Barone, M. Borghesi, G. Carapella, A. P. Caricato, I. Carusotto, W. Chung, A. Cian, D. Di Gioacchino, E. Enrico, P. Falferi, M. Faverzani, E. Ferri, G. Filatrella, C. Gatti, A. Giachero, D. Giubertoni, A. Greco, C. Kutlu, A. Leo, C. Ligi, P. Livreri, G. Maccarrone, B. Margesin, G. Maruccio, A. Matlashov, C. Mauro, R. Mezzena, A. G. Monteduro, A. Nucciotti, L. Oberto, S. Pagano, V. Pierro, L. Piersanti, M. Rajteri, A. Rettaroli, S. Rizzato, Y. K. Semertzidis, U. Uchaikin and A. Vinante

**Abstract**—The advent of ultra-low noise microwave amplifiers revolutionized several research fields demanding quantum-limited technologies. Exploiting a theoretical bimodal description of a linear phase-preserving amplifier, in this contribution we

analyze some of the intrinsic properties of a model architecture (i.e., an rf-SQUID based Josephson Traveling Wave Parametric Amplifier) in terms of amplification and noise generation for key case study input states (Fock and coherent). Furthermore, we present an analysis of the output signals generated by the parametric amplification mechanism when thermal noise fluctuations feed the device.

**Index Terms** - Microwave photonics, Noise figure, Superconducting microwave devices.

### I. INTRODUCTION

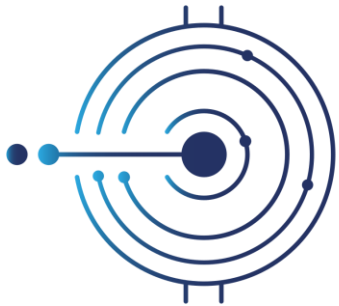
Nowadays, the technological progress in several fields of research, spanning from quantum computation and communi-

This work is supported by the Italian Institute of Nuclear Physics (INFN) within the Technological and Interdisciplinary research commission (CSNS), by the European Union's H2020-MSCA Grant Agreement No.101027746, by the Institute for Basic Science (IBS-R017-D1) of the Republic of Korea, by the University of Salerno - Italy under the projects FRB19PAGAN and FRB20BARON, by the SUPERGALAX project in the framework of the H2020-FETOPEN-2018-2020 call, and the Joint Research Project PARAWAVE of the European Metrology Programme for Innovation and Research (EMPIR). PARAWAVE received funding from the EMPIR

nat.supr-conj 30 Sep 2021

arXiv:2109.14924v1

L. Fasolo *et al.*, “Bimodal Approach for Noise Figures of Merit Evaluation in Quantum-Limited Josephson Traveling Wave Parametric Amplifiers”. *IEEE TAS (under major revisions)*.



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# DART WARS Annual Meeting

WP2: JTWPA Devices fabrication

*Emanuele ENRICO*

# PiQuET Laboratory



**500 m<sup>2</sup> Cleanroom**



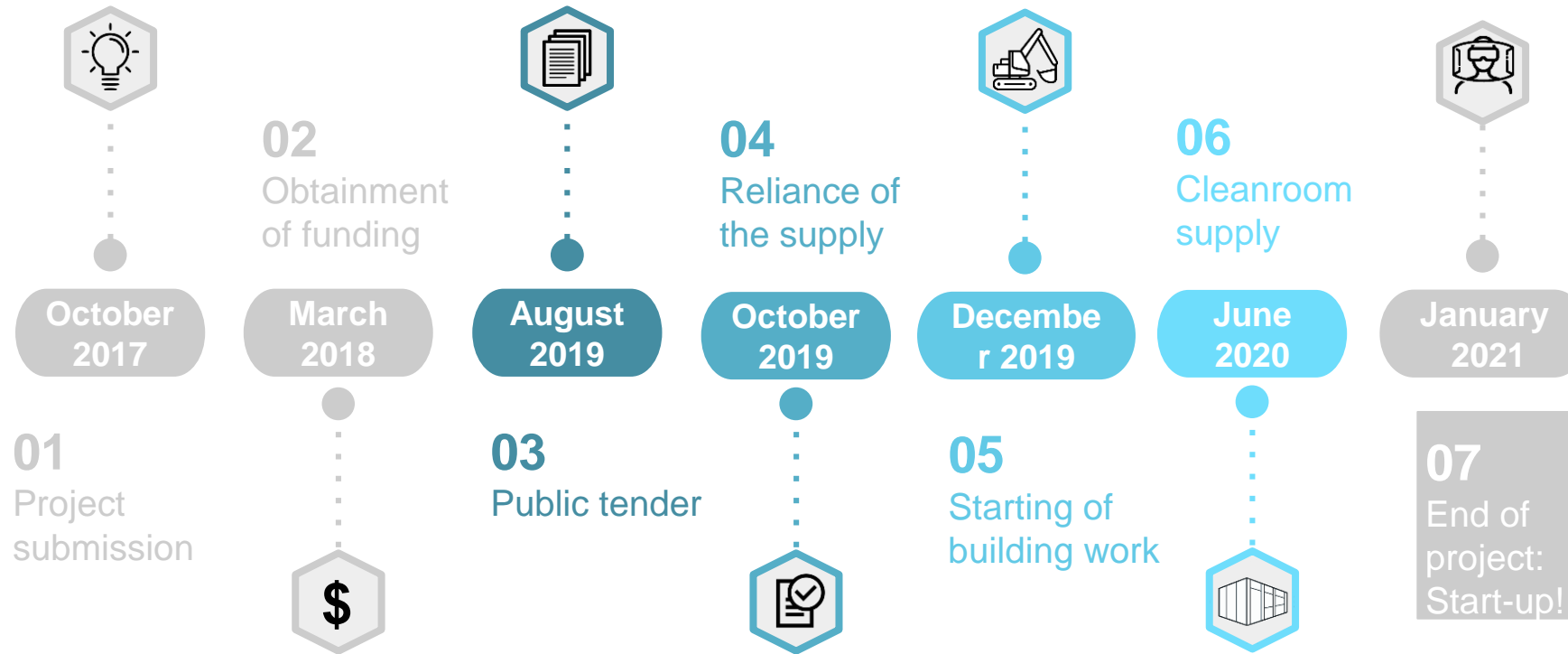
**POLITECNICO  
DI TORINO**



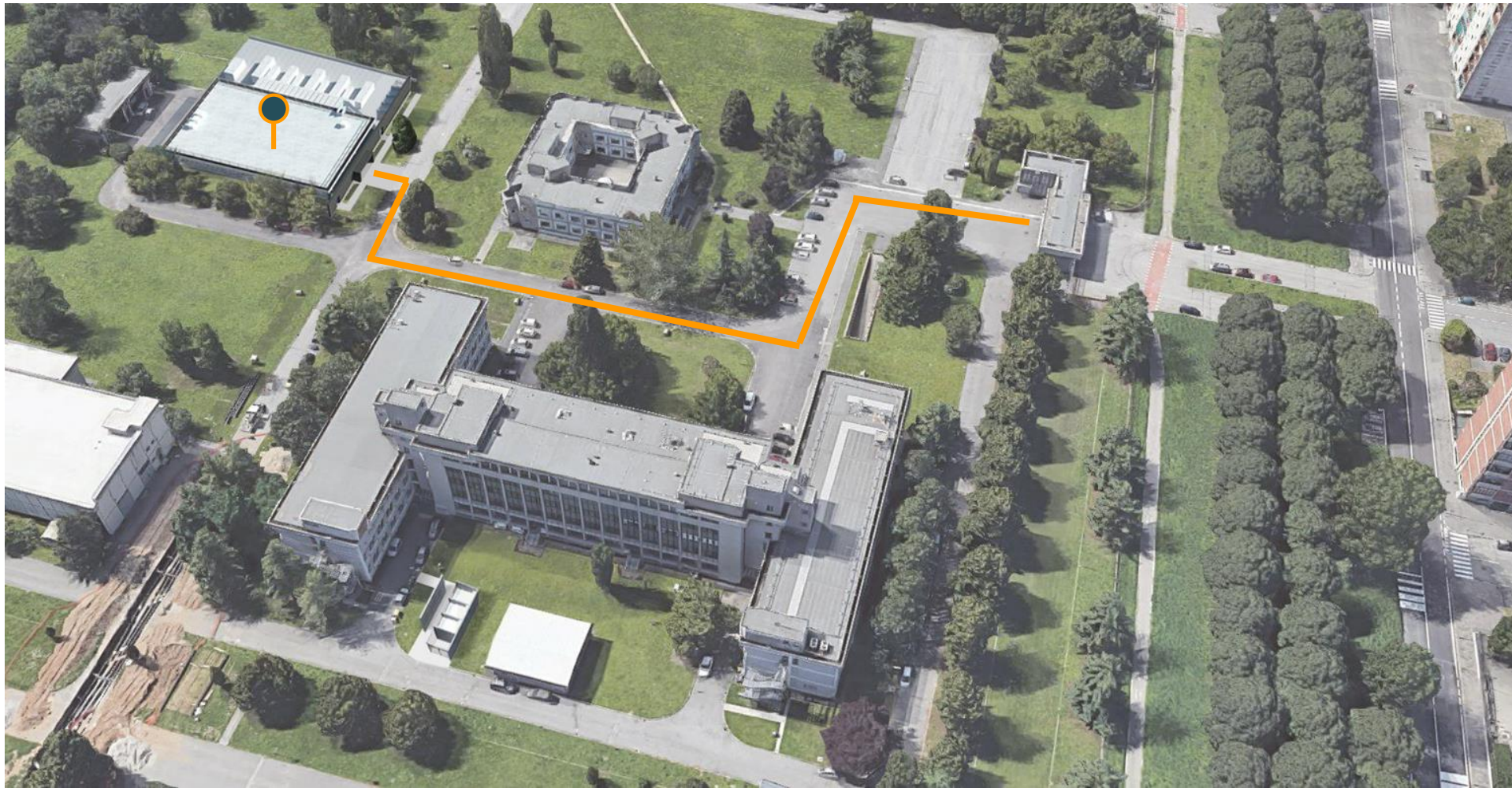
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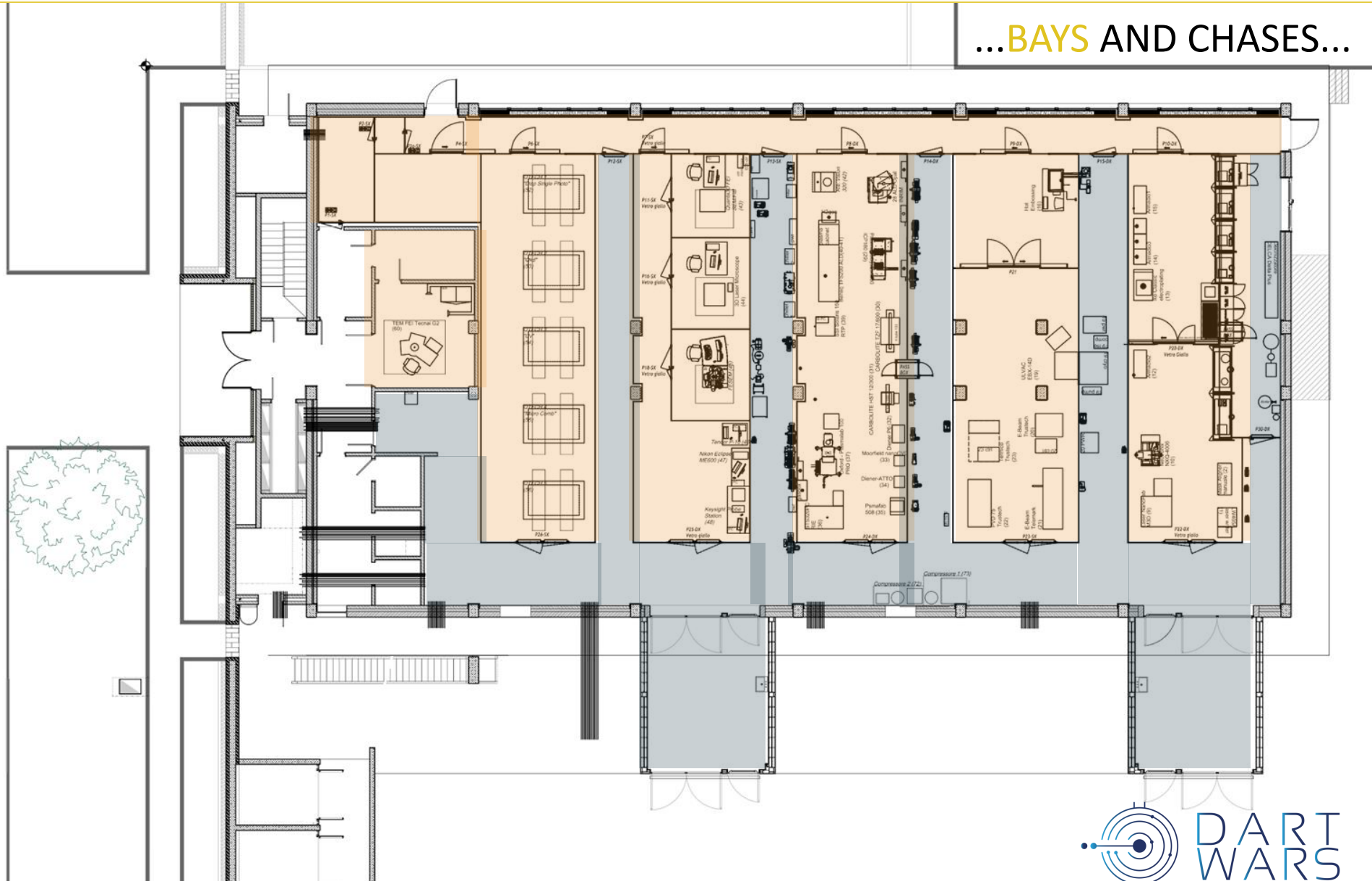


# INRiM Campus, Torino



# INRiM Campus, Torino

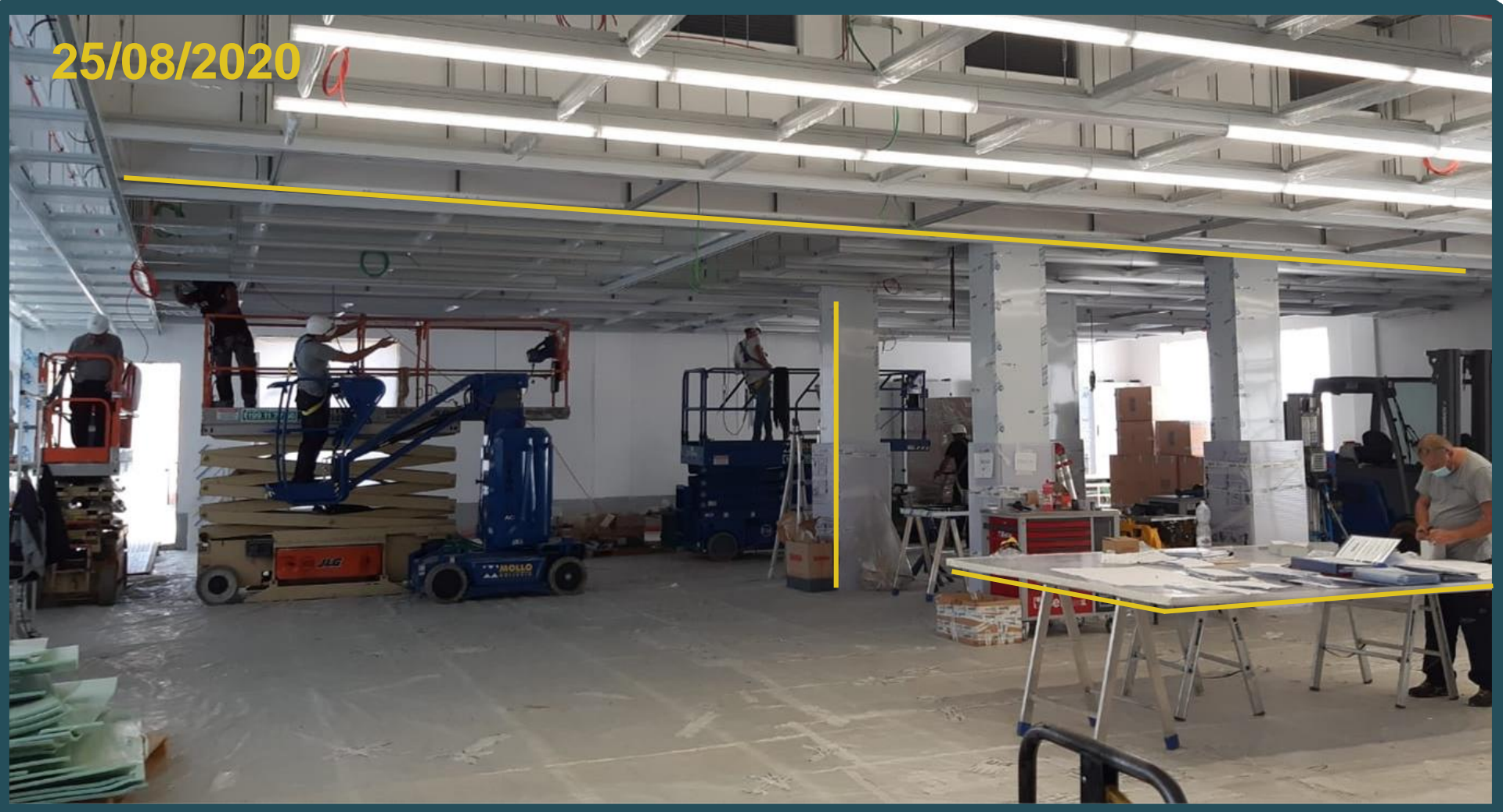
...BAYS AND CHASES...



# INRiM Campus, Torino



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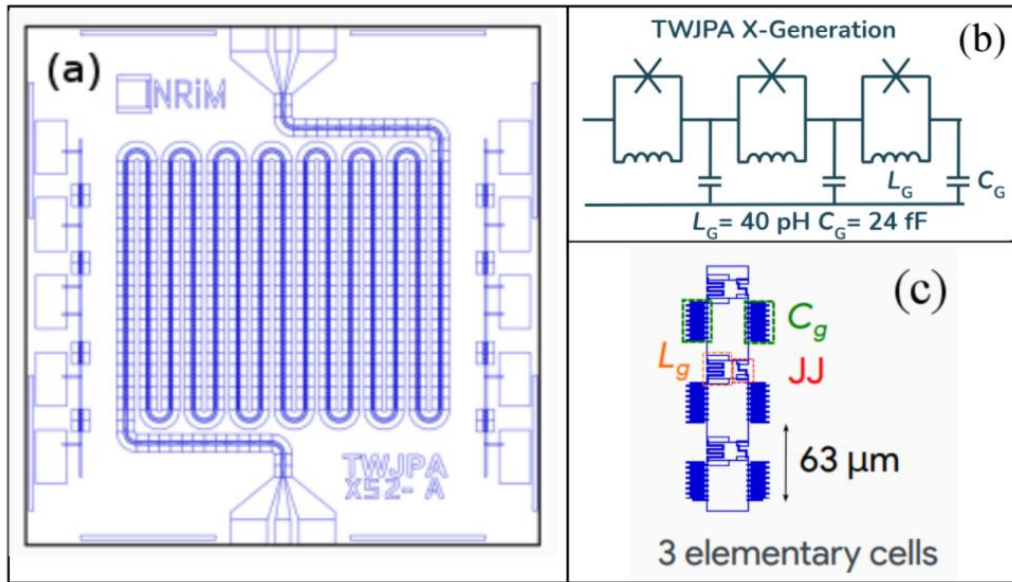




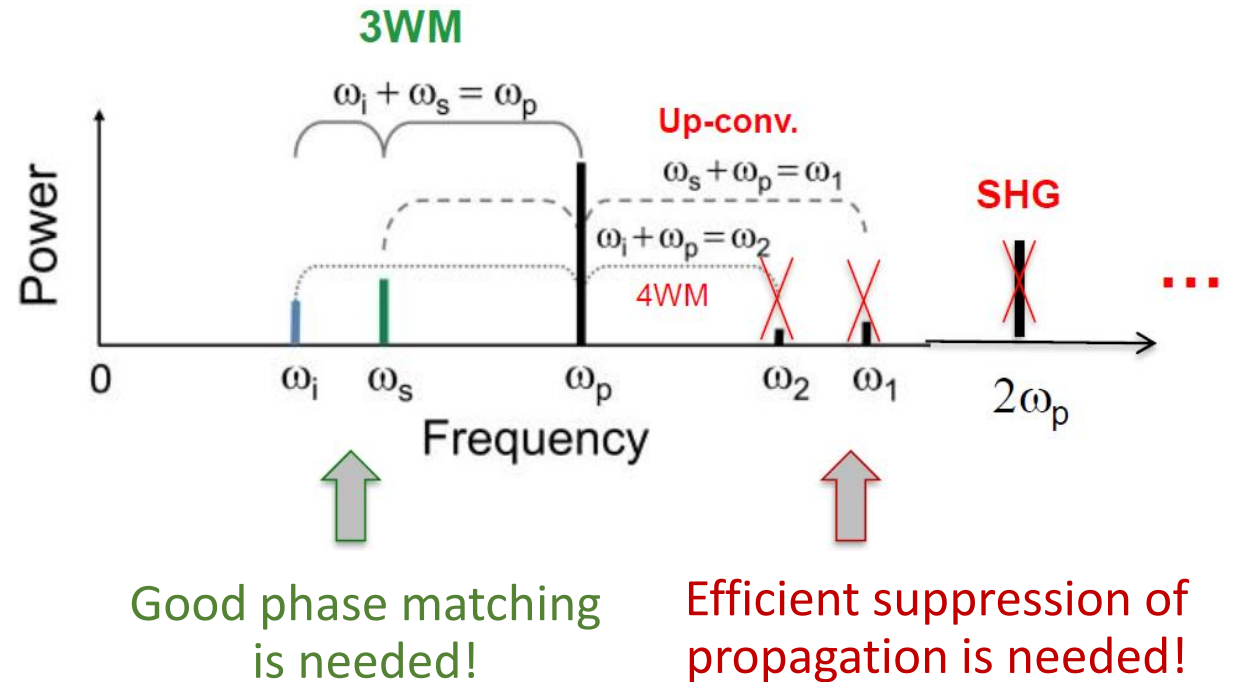
- 2 inches wafer standardization of the whole fabrication chain
- 12 chips per wafer (1x1 cm<sup>2</sup>)
- PiQuET wet processes migration
- PiQuET E-Beam evaporator installed and running (from may 2021)
- PiQuET Installation of Ebeam and Optical Litho expected by March 2022 (currently back-and-forth from the QR Lab@INRiM)



# Unwanted high-tone waves generation



First generation (X) preliminary tested at LNF & IBS

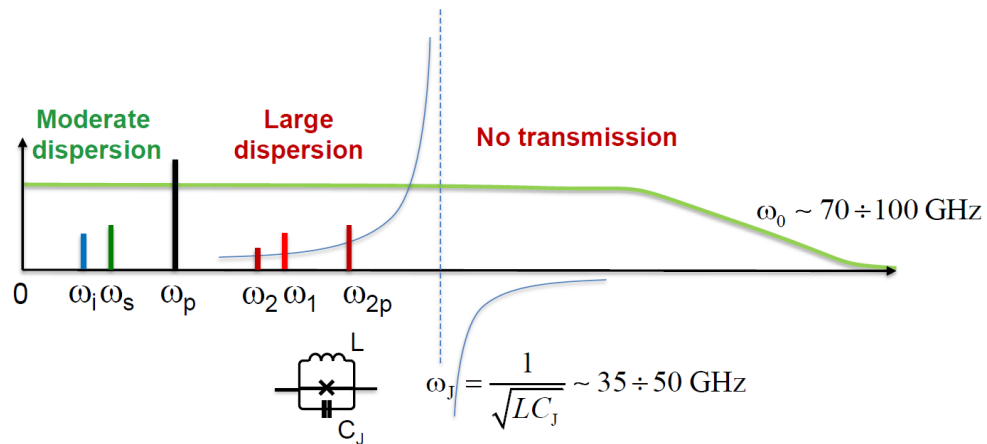


# Resonant Phase Matching Scheme

**Destroy** phase matching condition for up conversion :

$$k_{sum} = k_p + k_s + \Delta k$$

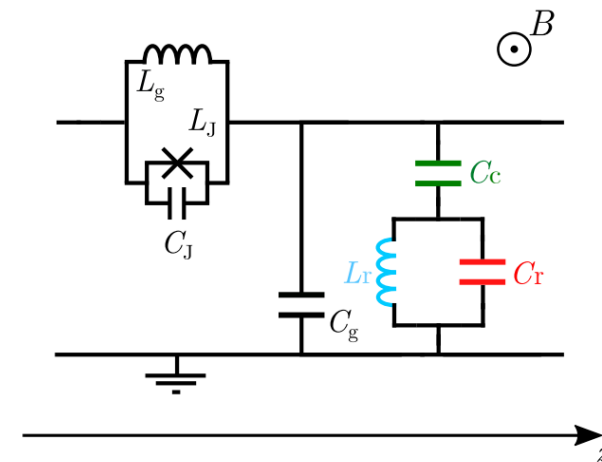
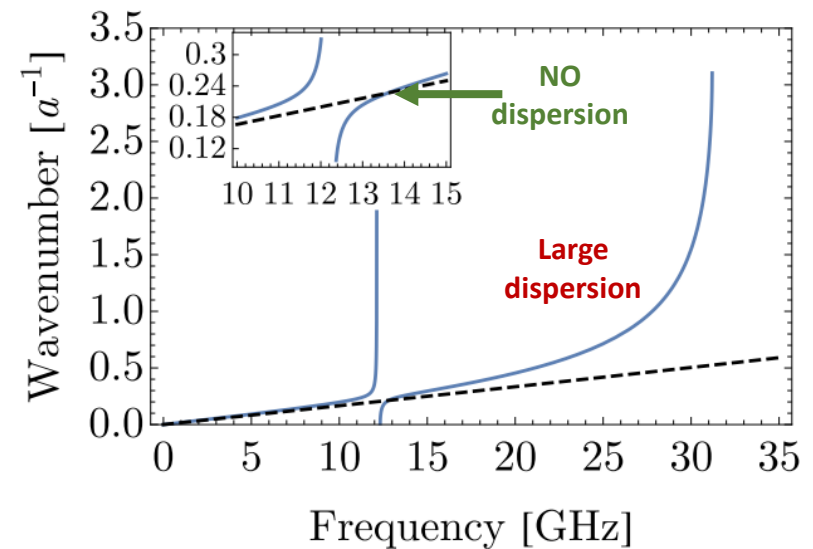
- By decreasing the plasma frequency



**Repair** phase matching condition for down conversion:

$$k_p = k_s + k_i + \Delta k - \Delta k$$

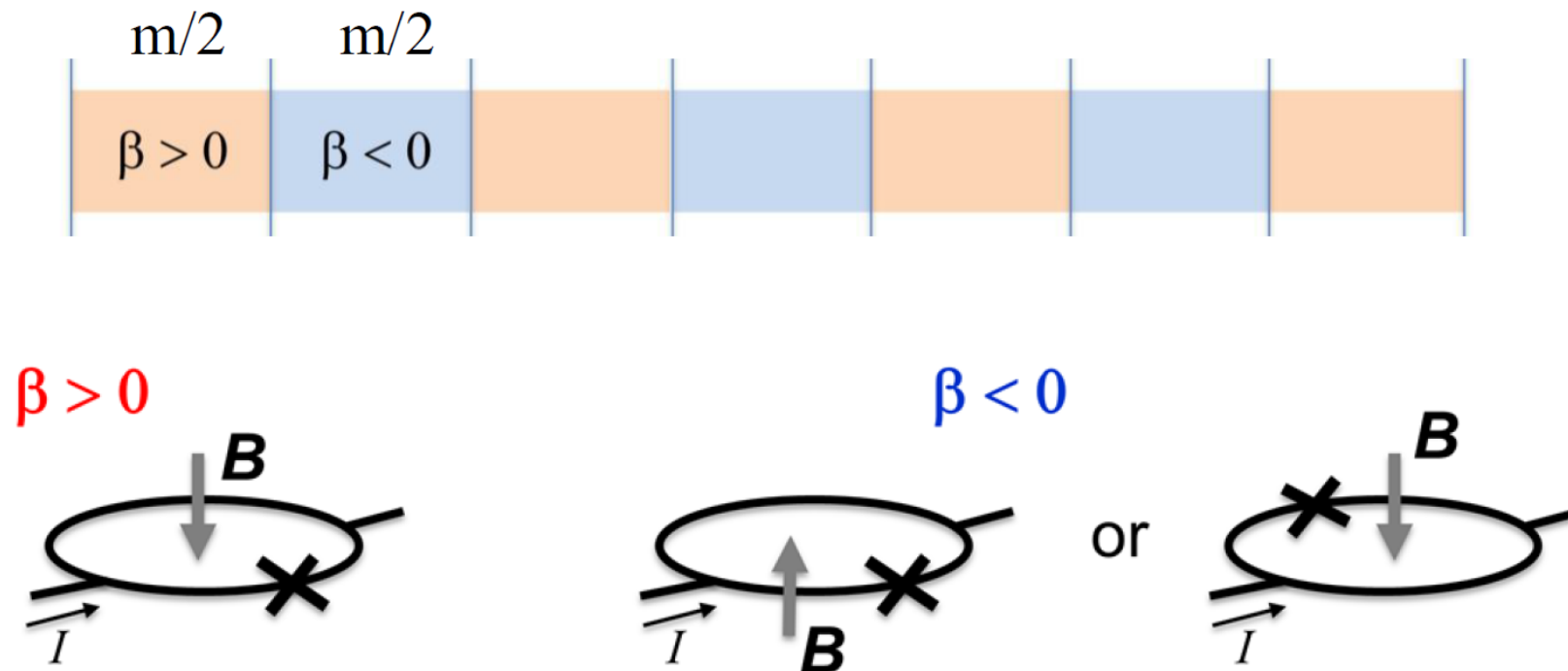
- By resonant phase matching (RPM) [O'Brien 2014]
- Resonators can be either lumped element [Macklin 2015] or distributed resonators [White 2015]



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# The poled Josephson transmission line

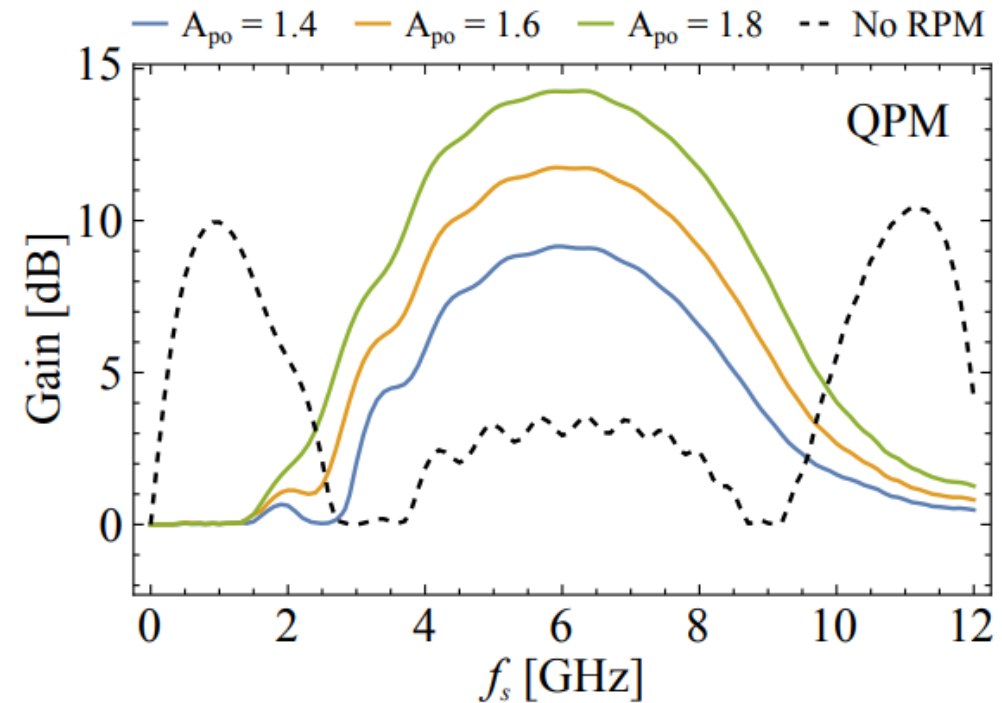
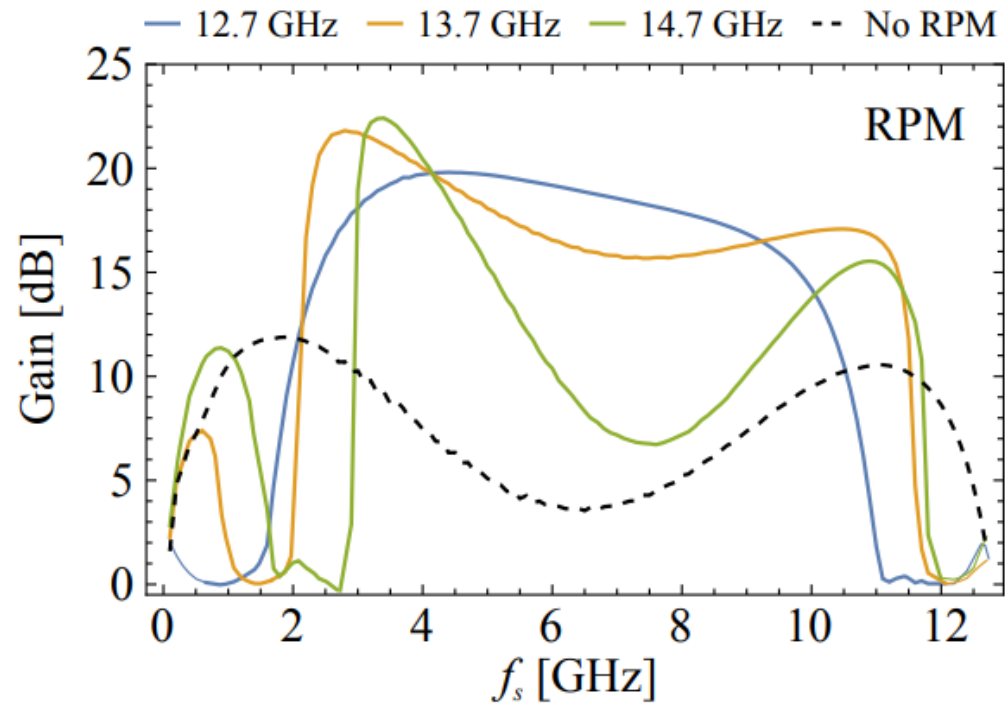


A.B. Zorin, "Quasi-phasematching in a poled Josephson traveling-wave parametric amplifier with three-wave mixing". Appl. Phys. Lett. 118, 222601 (2021).

$$\begin{aligned} \frac{dA_i}{dx} &= \frac{\beta_L}{4} \left( k_p k_s A_p A_s^* e^{i(k_p - k_s)x} + k_p k_{p+i} A_p A_{p+i}^* e^{i(k_p - k_{p+i})x} + k_{2p} k_{p+s} A_{2p} A_{p+s}^* e^{i(k_{2p} - k_{p+s})x} \right) e^{-ik_i x} \\ \frac{dA_s}{dx} &= \frac{\beta_L}{4} \left( k_p k_i A_p A_i^* e^{i(k_p - k_i)x} + k_p k_{p+s} A_p A_{p+s}^* e^{i(k_p - k_{p+s})x} + k_{2p} k_{p+i} A_{2p} A_{p+i}^* e^{i(k_{2p} - k_{p+i})x} \right) e^{-ik_s x} \\ \frac{dA_p}{dx} &= \frac{\beta_L}{4} \left( -k_s k_i A_s A_i^* e^{i(k_s + k_i)x} + k_s k_{p+s} A_s A_{p+s}^* e^{i(k_s - k_{p+s})x} + k_i k_{p+i} A_i A_{p+i}^* e^{i(k_i - k_{p+i})x} + \right. \\ &\quad \left. + k_{2p} k_p A_{2p} A_p^* e^{i(k_{2p} - k_p)x} \right) e^{-ik_p x} \\ \frac{dA_{p+i}}{dx} &= \frac{\beta_L}{4} \left( -k_p k_i A_p A_i^* e^{i(k_p + k_i)x} + k_{2p} k_s A_{2p} A_s^* e^{i(k_{2p} - k_s)x} \right) e^{-ik_{p+i} x} \\ \frac{dA_{p+s}}{dx} &= \frac{\beta_L}{4} \left( -k_p k_s A_p A_s^* e^{i(k_p + k_s)x} + k_{2p} k_i A_{2p} A_i^* e^{i(k_{2p} - k_i)x} \right) e^{-ik_{p+s} x} \\ \frac{dA_{2p}}{dx} &= \frac{\beta_L}{4} \left( -\frac{k_p^2 A_p^2}{2} e^{i(k_p + k_p)x} - k_{p+i} k_s A_{p+i} A_s^* e^{i(k_{p+i} + k_s)x} - k_{p+s} k_i A_{p+s} A_i^* e^{i(k_{p+s} + k_i)x} \right) e^{-ik_{2p} x} \end{aligned}$$

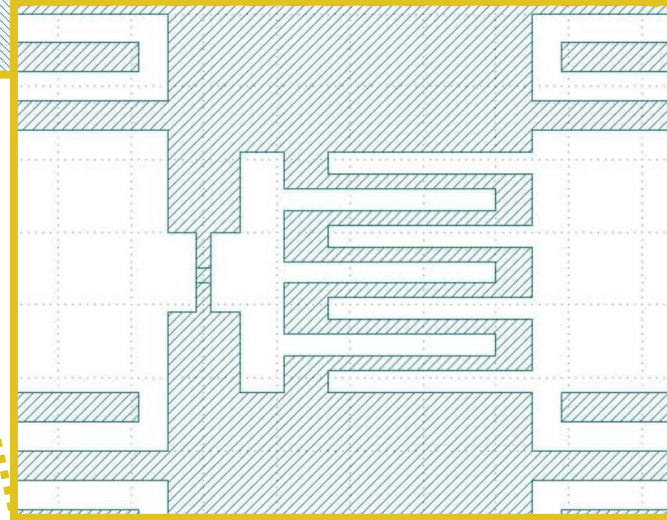
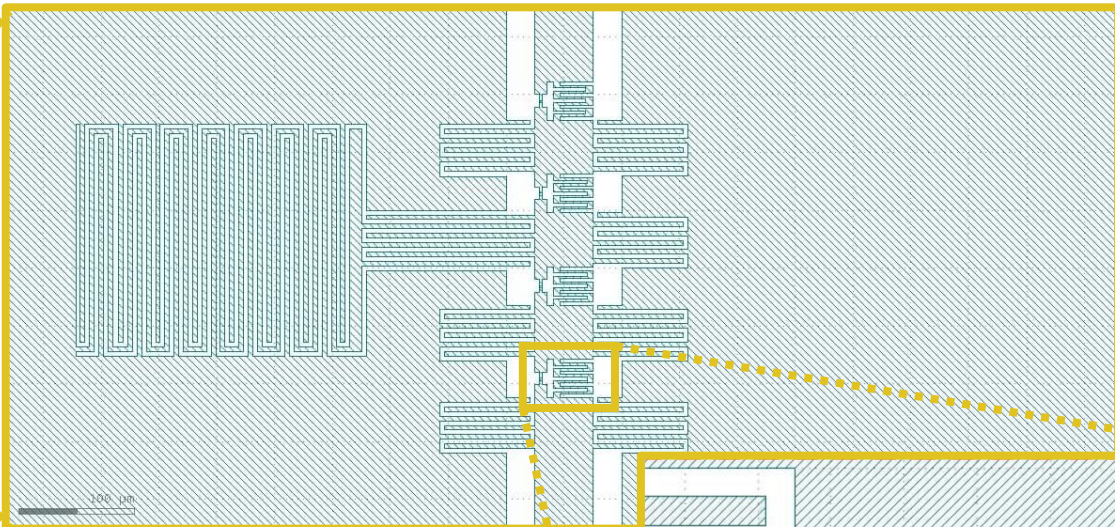
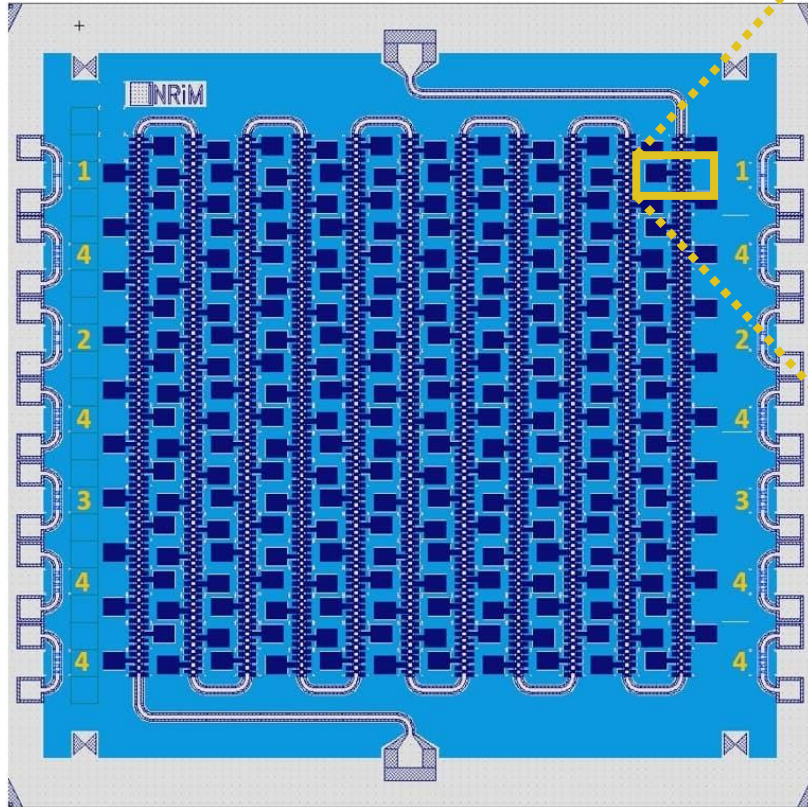
[1] T. Dixon *et. al.*, “Capturing Complex Behavior in Josephson Traveling-Wave Parametric Amplifiers”, Phys. Rev. Applied 14, 034058

# RPM and QPM – Classical CMEs



A. Giachero *et al.*, “Detector Array Readout with Traveling Wave Amplifiers”. **Submitted to JLT**.

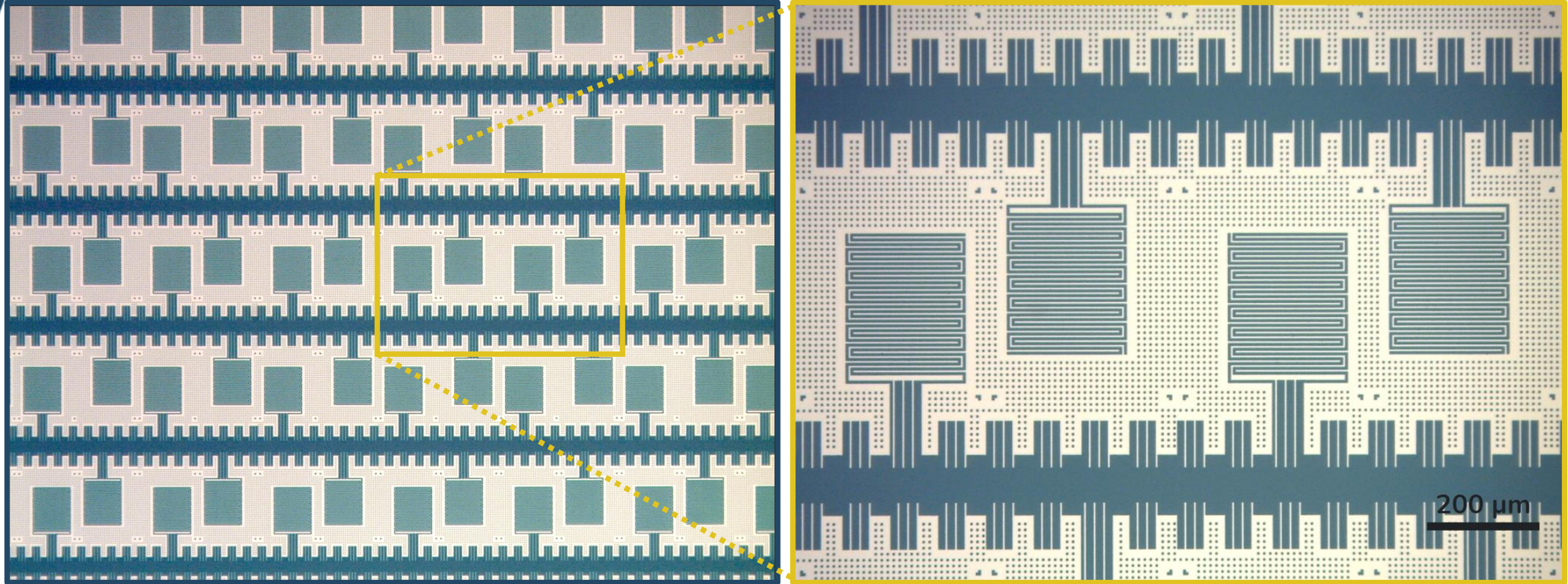
# JTWPA by 2-steps optical lithography



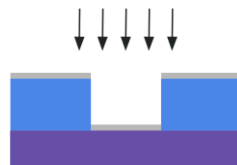
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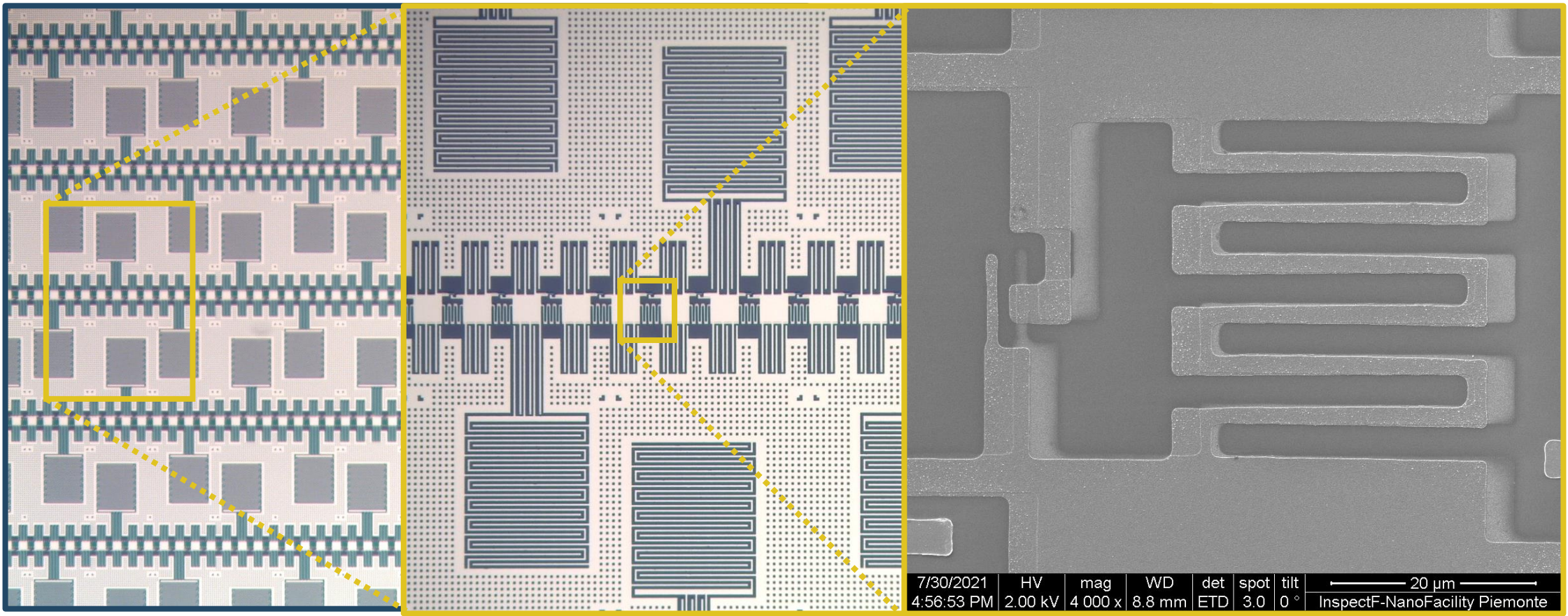
# JTWPA by 2-steps optical lithography



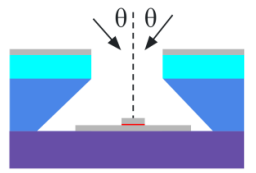
Single angle evaporation



# JTWPA by 2-steps optical lithography

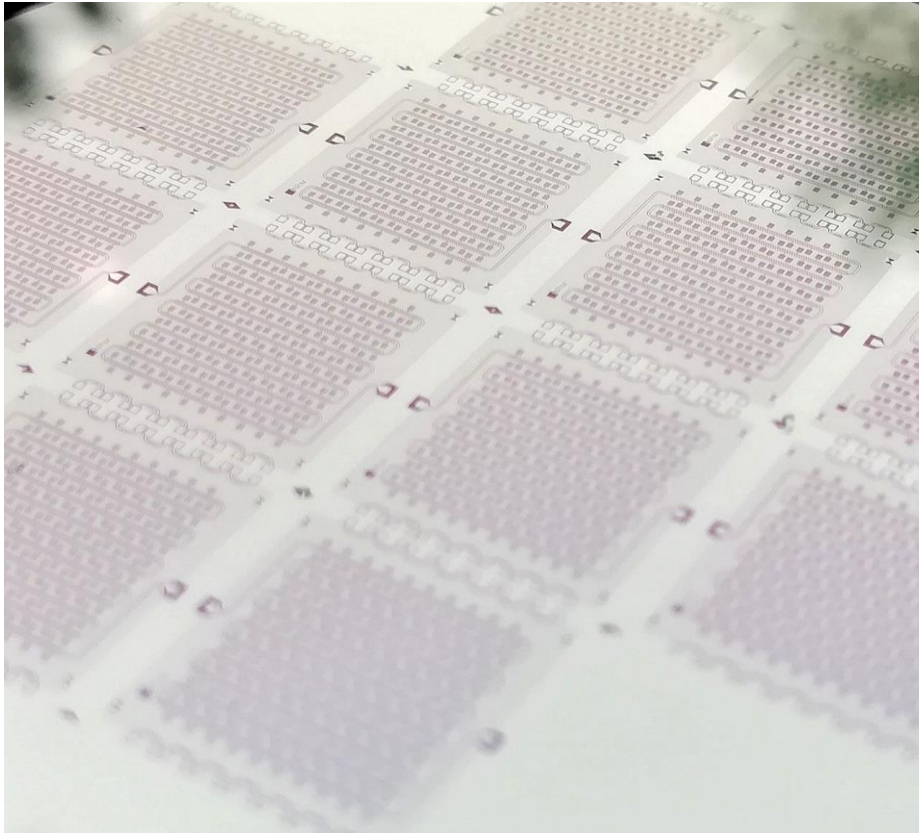


Double angle evaporation



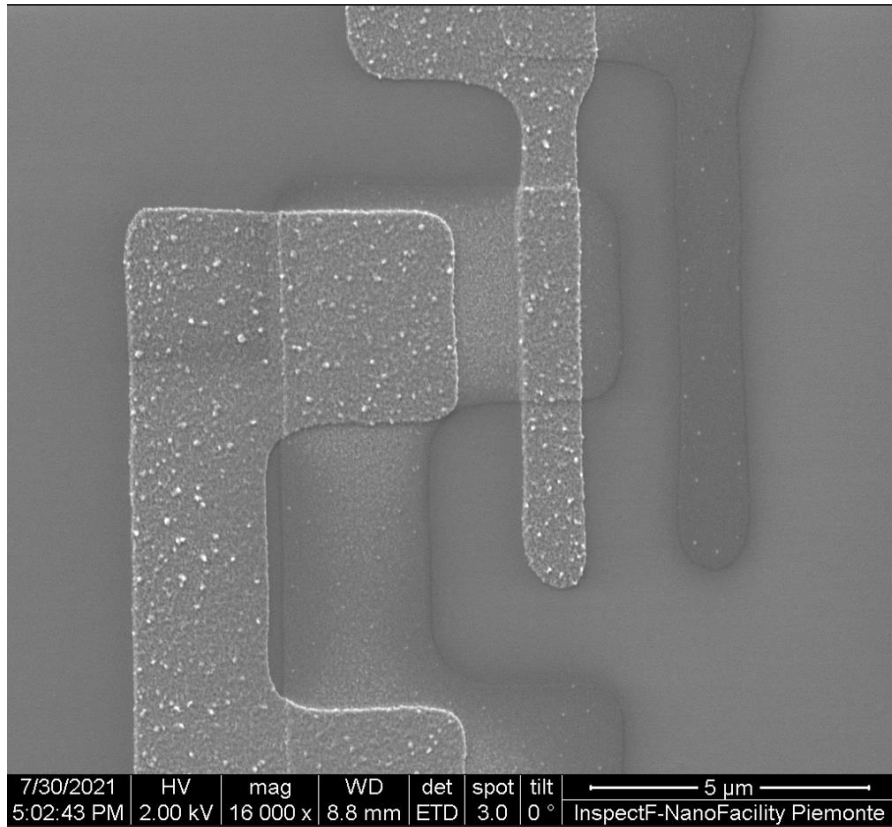


# JTWPA Architectures and Generations

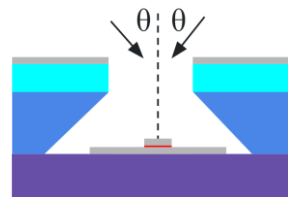


- JTWPA\_X
  - **\_RPM\_DielectricLess\_4uA\_1**
  - **\_RPM\_200SiO2\_2-5uA\_1**
  - **\_RPM\_100aSiH\_2-5uA\_1**
- JTWPA\_C
  - **\_RPM\_DielectricLess\_4uA\_1**
  - **\_QPM\_DielectricLess\_2uA\_1**
  - **\_RPM\_200SiO2\_2-5uA\_1**
  - **\_RPM\_100aSiH\_2-5uA\_1**
- JTWPA\_LS
  - **\_RPM\_200SiO2\_2-5uA\_1**
  - **\_RPM\_100aSiH\_2-5uA\_1**

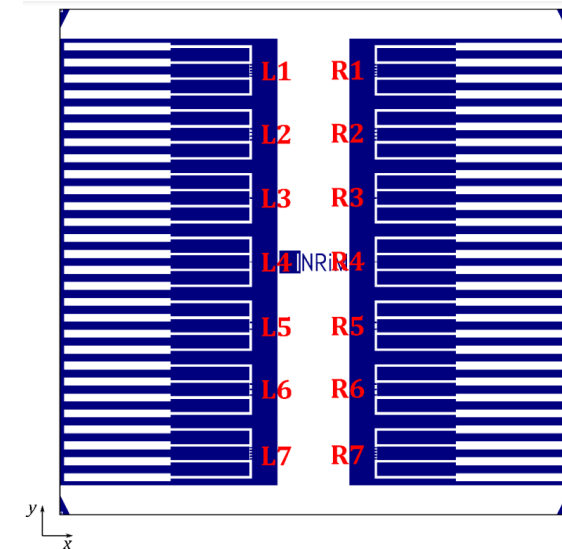
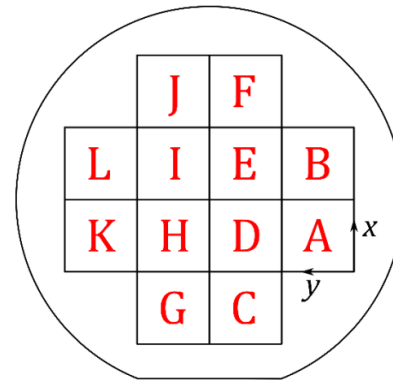
# JJs reproducibility



Double angle evaporation



ID	Device	Main Properties
Substrate 02	SQE_JJs_Reproducibility_Test_Array_4uA_225fF_1	Dynamic Oxidation/Diced
Substrate 05	SQE_JJs_Reproducibility_Test_Array_4uA_225fF_2	Static Oxidation/Not Diced
Substrate 06	SQE_JJs_Reproducibility_Test_Array_4uA_225fF_3	Test Wafer

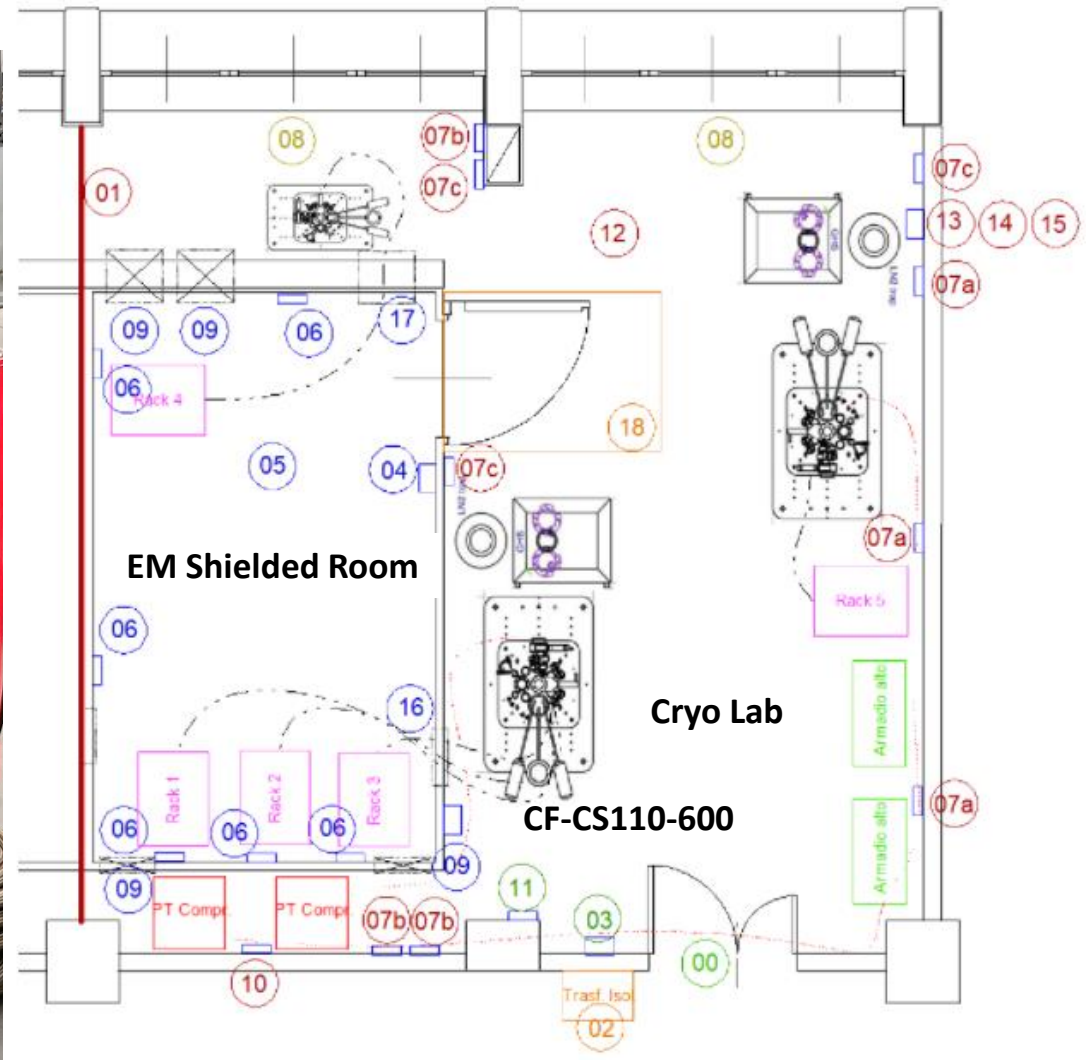


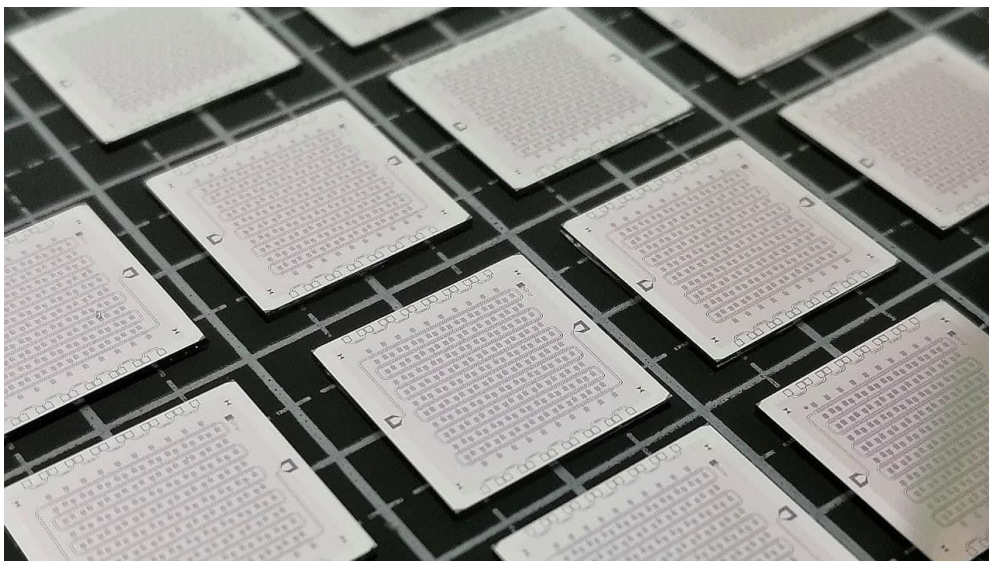
For further information (next talk):

WP4: Measurement at room temperature on the Josephson junctions

Labranca Danilo and Origo Luca

# Dry fridge – Expected January 2022





- JJs still to be refined
  - New RT measurement run in December
  - Then -> JJ test array ready to be delivered with proper  $I_c$  (beginning of January)
- Circuit parameters to be fine-tuned accordingly
  - SONNET simulations (in collaboration with INFN-UniMiB)
- JTWPA\_X and JTWPA\_C
  - New fabrication runs by the end of January 2022
- Chip Packaging
  - Flexible packaging still under development and characterization